A Unified Potentiostat for Electrochemical Glucose Sensors

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A unified potentiostat circuit for both \( \text{O}_2 \)- and \( \text{H}_2\text{O}_2 \)-based electrochemical glucose sensors was proposed and its function was verified by circuit simulations and measurement results of a fabricated chip. This circuit consisted of an operational amplifier, a comparator and current mirrors. The proposed circuit was fabricated with a 0.13 \( \mu \text{m} \) thick oxide CMOS process and an active area of 360 \( \mu \text{m} \times 100 \mu \text{m} \). The measurements revealed an input operation range from 0.5 V to 1.6 V in the \( \text{H}_2\text{O}_2 \)-based bio-sensor and from 1.7 V to 2.6 V in the \( \text{O}_2 \)-based bio-sensor with a supply voltage of 3.3 V. The evaluation results showed that the proposed potentiostat circuit is suitable for measuring the electrochemical cell currents of both \( \text{O}_2 \)- and \( \text{H}_2\text{O}_2 \)-based glucose sensors.

Keywords: Electrochemical cell, Glucose sensor, Potentiostat, Comparator, Current mirror

1. INTRODUCTION

Recently, the aging of the population has progressed rapidly with economic growth and the development of medical technology. Accordingly, the number of patients with chronic diseases, such as diabetes and cardiovascular diseases, has increased. As diabetes has high death rate, there is a strong need for portable measurement instruments that can diagnose diabetes easily.

Electrochemical sensors, optical sensors, piezoelectric sensors and acoustic sensors are used to measure the blood glucose for the diagnosis of diabetes [1]. Among them, the electrochemical sensor is used widely, because it is simple to manufacture with compact size and fast diagnosis.

An electrochemical glucose biosensor is based on the enzyme, glucose oxidase (GOD). This enzyme catalyzes the oxidation of glucose, which is a two step reaction process.

Two different types of electrochemical glucose biosensors are available on the market: an amperometric sensor and potentiometric sensor. The amperometric glucose sensor is based on measurements of electron flow during the oxidation or reduction, but the potentiometric sensor measures the potential changes in local pH during the reaction process. The amperometric glucose sensor is used most commonly due to its simple structure and low cost.

The amperometric electrochemical sensor consists of an electrochemical cell and a potentiostat, as shown in Fig. 1. The electrochemical cell consists of a working electrode (WE) onto which the reaction takes place, a reference electrode (RE) that maintains the constant potential, and a counter electrode (CE) that supplies the reaction current. The potentiostat supplies a desired cell potential \( V_{\text{cell}} \) between WE and RE, and measures the reaction current between the WE and CE [2].
Oxygen-electrode-based (O₂-based) and hydrogen-peroxide-electrode-based (H₂O₂-based) sensors are the two most widely used electrochemical glucose biosensors. In an O₂-based glucose sensor, when the cell potential V_cell between WE, made out of Pt, and RE, made out of Ag/AgCl, is typically -600 mV, WE emits electrons into solution by the reduction of oxidation at the surface of WE. Therefore, the output current is flowing from the CE to WE.

In the H₂O₂-based glucose sensor, when V_cell is typically +700 mV, WE absorbs electrons by the oxidation of hydrogen peroxide at the surface of WE. Therefore, the output current flows from the WE to CE [1].

Several configurations can be used to implement the potentiostat of an amperometric electrochemical sensor [3]. The method most commonly used is the use of a trans-impedance amplifier (TIA) that consists of two amplifiers. The first negative feedback amplifier is used to force V_cell to WE with reference to RE, and the second amplifier measures the current generated at WE. On the other hand, this technique requires the positive and negative input voltage to generate the current of both O₂-based and H₂O₂-based sensor, because the direction of the current generated in the O₂-based sensor is opposite to that of the current generated in the H₂O₂-based sensor.

Other configurations to implement the potentiostat use a current conveyor [4-7]. This involves the insertion of a resistor in the current path at WE, where the voltage drop is measured. Another approach for the current measurement in the potentiostat is the use of a current mirror [3]. This technique is easy to design and requires few components. On the other hand, two types of potentiostats need to measure the current generated in both O₂-based and H₂O₂-based glucose sensors.

In this paper, a unified potentiostat circuit, which can measure the current of both O₂-based and H₂O₂-based glucose sensors with one chip, was implemented using current mirrors. This potentiostat is very simple, has low power and a good measurement of current generated in both O₂-based and H₂O₂-based glucose sensors.

This paper is composed of five sections. The potentiostat based on a current mirror is explained in section II and the circuit design of the proposed potentiostat is described in section III. The evaluation results of the fabricated chip are shown in section IV, and finally, the conclusions are reported in section V.

2. CURRENT MIRROR BASED POTENTIOSTAT

Figure 2 shows the current mirror-based potentiostat circuit for an O₂-based glucose sensor.

The operational amplifier and MOSFET M1 were configured as a negative feedback loop through which the input voltage V_in = +600 mV was applied to the RE and WE is ground, then V_cell (V_cell = V_WE - V_RE) is -600 mV. Under these conditions, reaction current I_F flows from CE to WE and is copied to I_F1 by the current mirror, which consists of M1 and M2. The voltage drop was measured across R_m, which is proportional to the sensed current I_F. This potentiostat is very simple, has low power and a good measurement of current generated in both O₂-based and H₂O₂-based glucose sensors.

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3. CIRCUIT IMPLEMENTATION

New potentiostat topology that can generate the cell potential of two different O₂ and H₂O₂-based sensors using a current mir-
ror is described in this section. Figure 4 shows the proposed unified potentiostat that can manage opposite cell potentials and current flows in O₂ and H₂O₂-based sensors.

The proposed potentiostat consists of a comparator, an operational amplifier and two cascode-type current mirrors. The voltage of WE (V_CM) was set to half of the power supply voltage (V_DD/2) to obtain the maximum input dynamic range. The comparator checks the polarity of the cell potential, V_cell = V_WE - V_RE = V_CM - V_in, and deactivates the unnecessary current mirrors. The operational amplifier with MOSFETs MP1 and MN5 forms a negative feedback loop that keeps the potential of RE to V_in.

Figure 5 shows the equivalent circuit of potentiostat for the O₂-based sensor. In an O₂-based glucose sensor, V_in is set to V_DD/2 + 600 mV to get a negative V_cell(-600 mV) and the comparator output is low, because V_in > V_CM. Therefore, PMOS MP5 and MP6 are off and the PMOS current mirror MP1-MP4 is deactivated, but NMOS MN1 and MN2 are on and the NMOS current mirror MN3-MN6 and PMOS current mirror MP7-MP10 are activated. The reaction current I_f that flows from WE to CE is copied to R_M by cascode current mirrors, MN3-MN6 and MP7-MP10. The sensed current is determined by the voltage drop through R_M.

The operational amplifier was implemented by a folded cascode single stage amplifier that has only one pole to maximize the stability of the potential control loop, as shown in Fig. 7. The phase margin of this operational amplifier was approximately 82.8° and the open loop gain was 67.8 dB.

4. MEASUREMENT RESULTS

The proposed potentiostat circuit was verified by Cadence SPECTRE simulations using a 0.13 μm thick oxide CMOS process. The layout was performed using Cadence Virtuoso and verified using Mentor Calibre. Figure 8 shows the chip photography, which consists of a band gap reference, a comparator, an operational amplifier and an output stage. The area of the potentiostat...
The core was 360 μm × 100 μm.

Figure 9 shows the photography of the evaluation board, including a fabricated potentiostat chip, a parameter analyzer and an electrochemical cell of K₃Fe(CN)₆ solution.

First, we checked the performance of the fabricated chip with the electrical equivalent circuit of a three electrode electrochemical cell, instead of a K₃Fe(CN)₆ solution.

Figure 10 shows an electrical equivalent circuit of a three electrode electrochemical cell. In this model, the solution impedances are typically small and negligible. RC and RW represent the faradaic resistances, and CC and CW are the double layer capacitances associated with CE and WE, respectively.

These double layer capacitances and faradaic resistances depend on the area of the electrodes and the solution concentration [8]. They can be expressed by

\[ C_X = k_C A_X \]

where \( C_X \) is the capacitance of electrode X, \( A_X \) is the area of the electrode X, and \( k_C \) is a constant with an approximate value of 0.36 μF/㎟ [9]. \( R_W \) is defined as

\[ R_W = \frac{V_{cell}}{I_F} \]

We checked the operation of the proposed circuit with K₃Fe(CN)₆ solution, instead of the glucose solution, because the oxidation and reduction occur quickly in K₃Fe(CN)₆ solution. In contrast, in glucose, electrons are transferred very slowly and oxidation/reduction occurs slowly. Therefore, K₃Fe(CN)₆ solution is often used to check the operation of a potentiostat.

Figure 11 shows the cyclic voltammetry measurement of 10 mM K₃Fe(CN)₆ solution using a fabricated potentiostat. The commercial electrodes, which consist of WE (Pt) and RE (Ag/AgCl),
K₃Fe(CN)₆ solution.

Fig. 12. Cyclic voltammetry measurement result of the 10 mM K₃Fe(CN)₆ solution.

are used to sense the current reaction. When the cell voltage is increased from -1.6 V to +1.6 V, the maximum sensing current occurs at \( V_{cell} = -0.43 \) V. This means that this potentiostat drives the O₂-based electrochemical glucose sensor. The maximum sensing current occurs at \( V_{cell} = +0.56 \) V when cell voltage decreases from +1.6 V to -1.6 V. This means that this potentiostat drives the H₂O₂-based electrochemical glucose sensor. These results show the proposed potentiostat can drive both O₂ and H₂O₂-based electrochemical glucose sensors and detect the sensing current very well.

Table 1 summarizes the measurement results of the fabricated chip.

The performance of the proposed potentiostat is compared to that of other potentiostats in Table 2. The proposed potentiostat can drive both the O₂ and H₂O₂-based electrochemical glucose sensors, but other potentiostats can drive only the H₂O₂-based electrochemical glucose sensors with positive power supply.

The core area of the proposed potentiostat is the smallest, even though this potentiostat can drive two kinds of electrochemical glucose sensors. The power consumption of the proposed potentiostat was lower than that of other potentiostats, except Ref [10], whose power consumption was a simulation result without chip fabrication. So, the power consumption of Ref [10] cannot be confirmed. From these comparative results, the proposed potentiostat is superior to conventional potentiostats.

5. CONCLUSIONS

This paper reported a new potentiostat circuit that can drive and measure the currents of both O₂- and H₂O₂-based electrochemical glucose sensors with positive input voltage. In the proposed potentiostat, a one pole operational amplifier was used to obtain a stable feedback loop, which applies the cell potential, and cascode type current mirrors were used to achieve accurate copying of the reaction current. The proposed potentiostat was fabricated using a 0.13 \( \mu \)m thick oxide CMOS process. The fabricated potentiostat was verified using the electrical-equivalent circuit of the electrochemical cell. Test results showed that the current of the O₂-based sensor can be measured with the input voltage from 1.7 V to 2.6 V and that of the H₂O₂-based sensor could be measured with input voltage from 0.5 V to 1.6 V at a supply voltage of 3.3 V. The operation of the fabricated potentiostat was also confirmed using a K₃Fe(CN)₆ solution. These results show the proposed chip was a good potentiostat that can drive both O₂-based and H₂O₂-based glucose sensors.

ACKNOWLEDGMENTS

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REFERENCES


Table 1. Measurement summary of the proposed potentiostat.

<table>
<thead>
<tr>
<th>Process</th>
<th>0.13( \mu )m Thick Oxide CMOS</th>
</tr>
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<tbody>
<tr>
<td>Core Area</td>
<td>360 ( \mu )m \times 100 ( \mu )m</td>
</tr>
<tr>
<td>Power current consumption</td>
<td>148 ( \mu )A @VDD=3.3V</td>
</tr>
<tr>
<td>Input range</td>
<td>H₂O₂ based 0.3V-1.60V @VDD=3.3V</td>
</tr>
<tr>
<td>Cell voltage in 10mole K₃Fe(CN)₆ solution</td>
<td>-0.43V to +0.56V</td>
</tr>
<tr>
<td>Range of operating supply voltage</td>
<td>2.4V-3.6V</td>
</tr>
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Table 2. Performance comparison between the proposed potentiostat and other potentiostats.

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<tr>
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<tbody>
<tr>
<td>Core Area</td>
<td>0.036 ( \mu )m</td>
<td>-</td>
<td>0.087 ( \mu )m</td>
<td>0.16 ( \mu )m</td>
</tr>
<tr>
<td>Power consumption</td>
<td>489 ( \mu )W</td>
<td>115 ( \mu )W</td>
<td>19,000 ( \mu )W</td>
<td>397 ( \mu )W</td>
</tr>
<tr>
<td>VDD</td>
<td>3.3V</td>
<td>1.8V</td>
<td>5.0V</td>
<td>3.3V</td>
</tr>
<tr>
<td>IDD</td>
<td>148 ( \mu )A</td>
<td>64 ( \mu )A</td>
<td>3.8 ( \mu )A</td>
<td>181 ( \mu )A</td>
</tr>
<tr>
<td>Detect sensor</td>
<td>O₂ based</td>
<td>H₂O₂ based</td>
<td>H₂O₂ based</td>
<td>H₂O₂ based</td>
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